

4th Generation 1200 V, 20 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Package Types: TO-247-2 Marking: C4D20120H

Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior

Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings ($T_c = 25^{\circ}$ C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	1200	- V			
DC Blocking Voltage	V _{DC}	1200	V			
		54		T _c = 25 °C		
Continuous Forward Current	I _F	26		T _c = 135 °C	Fig. 3	
		20		T _c = 156 °C		
Repetitive Peak Forward Surge Current		86		T _c = 25 °C, t _p = 10 ms, Half Sine Wave		
	FRM	56	Α	$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, Half Sine Wave}$		
Non-Repetitive Forward Surge Current	I _{FSM}	130		T _c = 25 °C, t _p = 10 ms, Half Sine Wave	F:~ 0	
		104		$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, Half Sine Wave}$	Fig. 8	
Non-Repetitive Peak Forward Surge Current	l _{F,Max}	1150		$T_{c} = 25 {}^{\circ}\text{C}, t_{p} = 10 \mu\text{s}, \text{Pulse}$		
		950		$T_{c} = 110 {}^{\circ}\text{C}, t_{p} = 10 \mu\text{s}, \text{Pulse}$		
Power Dissipation	P _{tot}	246	W	T _c = 25 °C	Fig. 4	
		106.5		T _c = 110 °C		
i²t Value	∫ i²t	84.5	A ² s	$T_{c} = 25 ^{\circ}\text{C}, t_{p} = 10 \text{ms}$		
		54		$T_{c} = 110 {}^{\circ}\text{C}, t_{p} = 10 \text{ms}$		

Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes	
Forward Voltage	V	1.5	1.8	V	I _F = 20 A, T _j = 25 °C	Fig. 1	
	V_{F}	2.2	3		I _F = 20 A, T _j = 175 °C		
Dovorco Current		35	200	μА	V _R = 1200 V, T _j = 25 °C	Fig. 2	
Reverse Current	I _R	65	400		V _R = 1200 V, T _j = 175 °C	Fig. 2	
Total Capacitive Charge	Q _c	99		nC	V _R = 800 V, T _j = 25 °C	Fig. 5	
		1500			$V_R = 0 \text{ V, T}_j = 25 \text{ °C, f} = 1 \text{ MHz}$		
Total Capacitance	С	93		pF	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6	
		67			$V_R = 800 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$		
Capacitance Stored Energy	E _c	28		μJ	V _R = 800 V	Fig. 7	

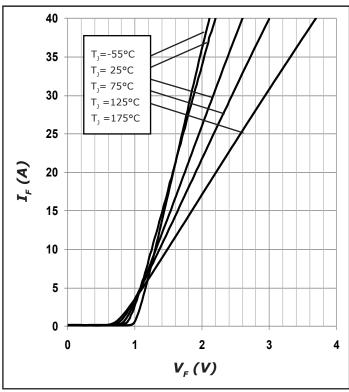
Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	$R_{\theta, JC (TYP)}$	0.61	°C/W	
Junction Temperature	T _j	-55 to +175		
Case & Storage Temperature	T _c	-55 to +150	°C	
Maximum Processing Temperature	T _{PROC}	325		10 min max.
TO 247 Mounting Targue		1	Nm	M3 Screw
TO-247 Mounting Torque	-	8.8	lbf-in	6-32 Screw

Typical Performance





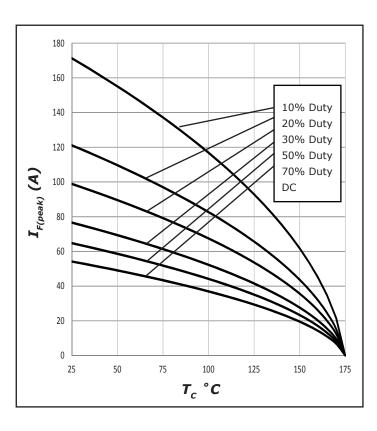
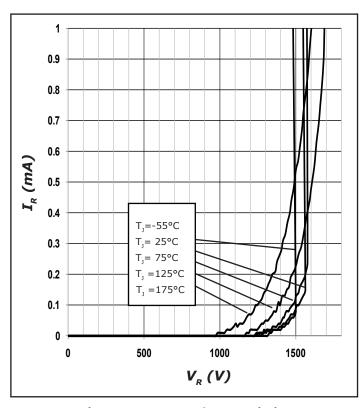


Figure 3. Current Derating



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Figure 2. Reverse Characteristics

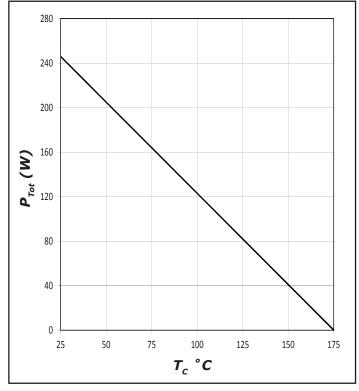


Figure 4. Power Derating

Typical Performance

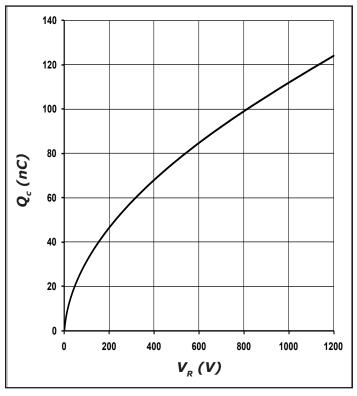
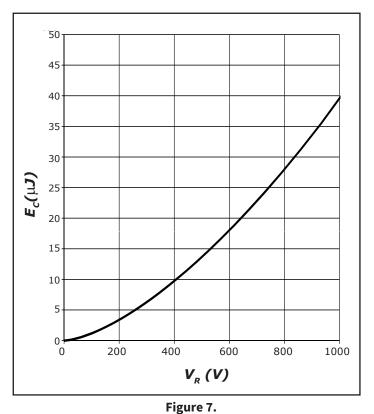


Figure 5.
Total Capacitance Charge vs. Reverse Voltage



Typical Capacitance Stored Energy

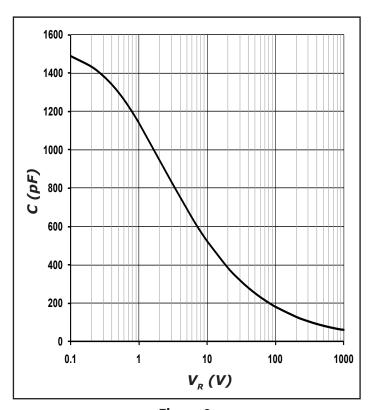


Figure 6.
Capacitance vs. Reverse Voltage

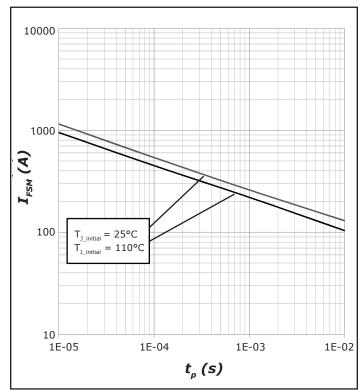


Figure 8. Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

Typical Performance

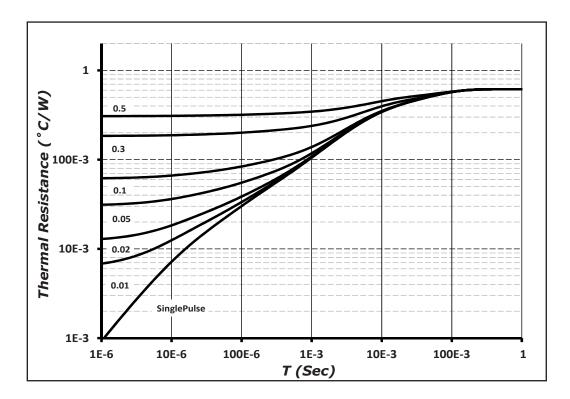
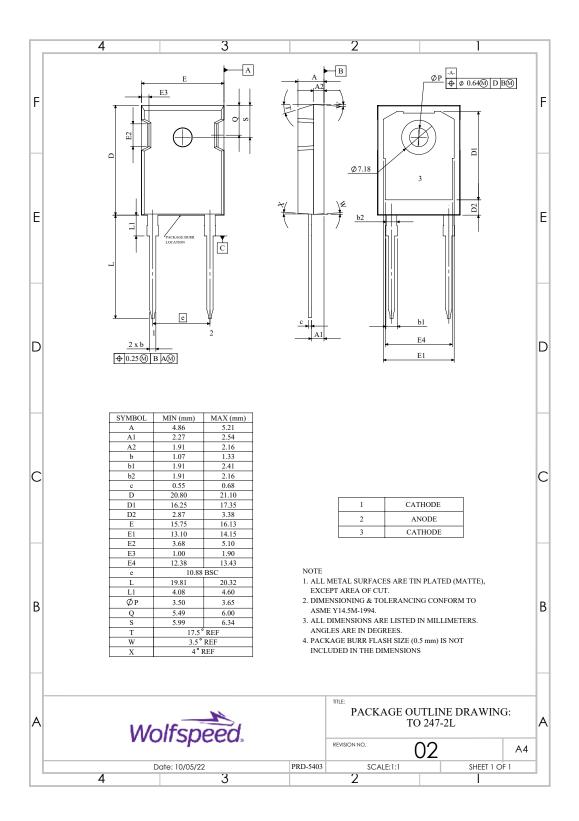


Figure 9
Transient Thermal Impedance

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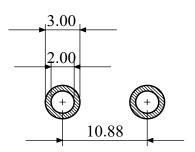
Package Dimensions & Pin-Out

Package: TO-247-2 (All dimensions are in mm)



Recommended Solder Pad Layout

(All dimensions are in mm)



Product Ordering Information

Order Number	Packing Type
C4D20120H	Tube

REACh, RoHS, and Halogen-Free compliance documentation available for this product.

Revision History

Document Version	Date of Release	Description of changes	
1	January - 2019	Initial Release	
2	November-2022	Update package drawing	

Notes & Disclaimer

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